# PGT 203 26

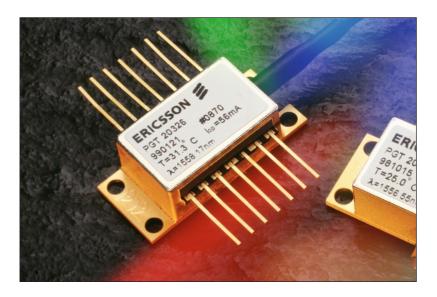
# DFB/EA Laser Module for 2.5 Gb/s Applications

#### **Key Features**

- L-band DFB CW source monolithicly integrated with an Electro Absorptionmodulator (EA)
- Hermetic, 14 pin butterfly package
- Single-mode fiber pigtail
- 4 GHz typical bandwidth
- -3 dBm output power

#### **Applications**

- 2.5 Gb/s
- L-band



#### Description

The laser module, intended for L-band DWDM applications at OC-48/STM-16, consists of a DFB laser with integrated absorption modulator mounted in a high speed package including isolator. Laser wavelengths are available according to the ITU-T grid.

# ERICSSON 🔰

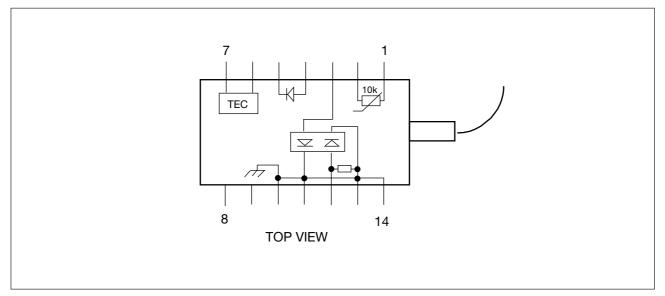


Figure 1. Block diagram

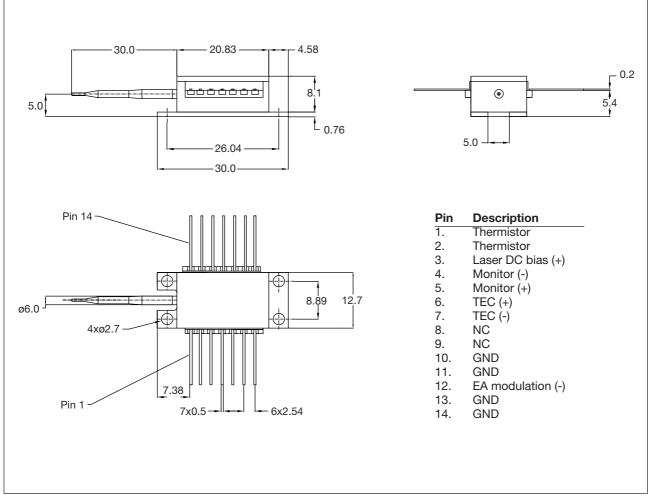


Figure 2. Mechanical outline and pin description

## **Optical Characteristics**

Electrical and optical characteristics at recommended operating conditions, unless otherwise noted.

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Wavelength		λ	1565		1615	nm
Output power	BOL	Pout	-3			dBm
Extinction ratio	2.5 V <sub>pp</sub>	ER	10			dB
Dispersion penalty	@ 6500 ps/nm disp.				1.5	dB
Side mode suppr.ratio		SMSR	35			dB
Optical isolation			30			dB

#### **Electrical Characteristics**

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Operating Current		l <sub>op</sub>	50		100	mA
Treshold Current		l <sub>th</sub>			25	mA
Forward Voltage		V <sub>f</sub>			2	V
Reflection E/E	0-3 GHz	S <sub>11</sub>			-10	dB
Small signal modulation bandwidth	-3 dB <sub>e</sub>	f <sub>c</sub>	3			GHz
Rise/Fall time	20/80%	t <sub>r</sub> /t <sub>f</sub>			125	ps
Monitor current			0.1		1	mA
Monitor dark current	-5 V			5	100	nA
Thermistor resistance	@ 25 °C		9.5		10.5	kΩ
TEC Voltage			-2.5		2.5	V
Current			-1.2		1.2	A
Power					3	W

#### **Operating Conditions**

Parameter	Symbol	Min	Тур	Max	Unit
Operating Case Temperature	T <sub>Case</sub>	0		70	°C
Operating Chip Temperature	T <sub>op</sub>	20		35	°C

### **Absolute Maximum Ratings**

Parameter	Symbol	Min	Max	Unit
Storage Temperature, maximum duration 12 months	T <sub>Stg</sub>	-40	85	°C
Laser forward current	I <sub>LD</sub>		150	mA
Modulator voltage	$V_{mod}$	-4	1	V

CAUTION: Stresses outside those listed in "Absolute Maximum Ratings" may cause permanent damage to the device.

# PGT 203 26

#### **Handling Precautions**

This device may be damaged as a result of electrostatic discharge (ESD). Take proper precautions during both handling and testing. This typically includes grounded wrist wraps, workbenches and floor mats in ESD controlled areas. Semiconductor devices may be damaged by current surges, use appropriate transient protection.

#### **Quality Assurance**

Ericsson Microelectronics commitment to quality has been proven through a decade of semiconductor device production and has been confirmed to ISO 9001. Opto product qualification is made according to the intention of applicable Telcordia standards.

#### **Connector Options**

FC/PC SC (Other connectors available on request)



Information given in this data sheet is believed to be accurate and reliable. However no responsibility is assumed for the consequences of its use nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Ericsson Microelectronics. These products are sold only according to Ericsson Microelectronics' general conditions of sale, unless otherwise confirmed in writing.

Product specifications subject to change without notice.

Ericsson Microelectronics AB SE-164 81 Kista, Sweden Telephone: +46 8 757 50 00 www.ericsson.com/microelectronics

For local sales contacts, please refer to our website or call: Int + 46 8 757 47 00, Fax: +46 8 757 47 76